Unit in mm

**TENTATIVE** 

TOSHIBA TRANSISTOR SILICON NPN EPITAXIAL PLANAR TYPE

# 2 S C 5 3 2 1

VHF~UHF BAND LOW NOISE AMPLIFIER APPLICATIONS

Low Noise Figure: NF = 1.4 dB (f = 2 GHz)
 High Gain: |S<sub>21e</sub>|<sup>2</sup> = 10 dB (f = 2 GHz)

MAXIMUM RATINGS ( $Ta = 25^{\circ}C$ )

CHARACTERISTIC	SYMBOL	RATING	UNIT
Collector-Base Voltage	$v_{CBO}$	8	V
Collector-Emitter Voltage	$v_{CEO}$	5	V
Emitter-Base Voltage	$V_{ m EBO}$	1.5	V
Collector Current	$I_{\mathbf{C}}$	10	mA
Base Current	$I_{\mathbf{B}}$	5	mA
Collector Power Dissipation	$P_{\mathbf{C}}$	100	mW
Junction Temperature	$T_{j}$	125	$^{\circ}\mathrm{C}$
Storage Temperature Range	$\mathrm{T_{stg}}$	-55~125	$^{\circ}\mathrm{C}$

#### MARKING



## MICROWAVE CHARACTERISTICS (Ta = 25°C)

	Onit in inin
2.0±0.2 1.3±0.1 0.655 0.65 1.5±0.1	2.1 ± 0.1 1.25 ± 0.1 0 0 + 1 0 0 - 1 0 0 0 0 - 1 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0
0.90 ± 0.1	0~0.1
1. BASE 2. EMITTE 3. COLLEG	
JEDEC	_
EIAJ	SC-70
TOSHIBA	2-2E1A

1001111	711		
Weight	• (	0.006	ø

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Transition Frequency	$ m f_{T}$	$V_{CE} = 3 V$ , $I_{C} = 7 mA$	9	_	_	GHz
I incortion (ioin	$ S_{21e} ^2$ (1)	$V_{CE} = 3 V, I_{C} = 7 \text{ mA}, f = 1 \text{ GHz}$	12.5	15.5	_	dB
	$ S_{21e} ^2$ (2)	$V_{CE} = 3 V$ , $I_{C} = 7 mA$ , $f = 2 GHz$	7	10	_	l ap
Noise Figure	NF (1)	$V_{CE} = 3 V$ , $I_{C} = 3 mA$ , $f = 1 GHz$	_	0.9	1.8	dB
Noise rigure	NF (2)	$V_{CE} = 3 V$ , $I_{C} = 3 mA$ , $f = 2 GHz$	_	1.4	2.2	иь

## ELECTRICAL CHARACTERISTICS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Collector Cut-off Current	$I_{CBO}$	$V_{CB} = 8 V, I_{E} = 0$	_	_	1	$\mu$ A
Emitter Cut-off Current	$I_{ m EBO}$	$V_{EB} = 1 V, I_C = 0$	_	_	1	$\mu$ A
DC Current Gain	$_{ m hFE}$	$V_{CE} = 3 V, I_{C} = 7 mA$	50	_	250	V
Output Capacitance	$C_{ob}$	$V_{CB} = 2.5 V, I_{E} = 0,$	_	0.4	_	pF
Reverse Transfer Capacitance	$\mathrm{C_{re}}$	f = 1 MHz (Note)	_	0.3	0.7	pF

(Note):  $C_{re}$  is measured by 3 terminal method with Capacitance bridge.

### CAUTION

This device electrostatic sensitivity. Please handle with caution.

2001-05-31

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